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Product data sheet

1. Product profile

1.1 General description

Ultrafast epitaxial power diode in a SOD141 (DO-201AD) axial lead plastic package.

1.2 Features and benefits

- Axial leaded plastic package
- Fast switching
- High voltage capability

1.3 Applications

 Discontinuous Current Mode (DCM) Power Factor Correction (PFC)

1.4 Quick reference data

- Low forward voltage drop
- Low thermal resistance
- Soft recovery characteristic
- High frequency switched-mode power supplies

Quick reference data					
Parameter	Conditions	Min	Тур	Max	Unit
repetitive peak reverse voltage		-	-	600	V
average forward current	square-wave pulse; $\delta = 0.5$; see <u>Figure 1</u> ; see <u>Figure 2</u>	-	-	4	А
racteristics					
forward voltage	I _F = 4 A; T _j = 25 °C; see <u>Figure 4</u>	-	-	1.28	V
characteristics					
reverse recovery time	$ I_F = 1 A; V_R = 30 V; dI_F/dt = 50 A/\mu s; T_j 25 °C; Ramp Recovery; see Figure 5 $	-	33	65	ns
	$ I_R = 1 \text{ A}; I_F = 0.5 \text{ A}; I_{R(meas)} = 0.25 \text{ A}; T_j = 25 \text{ °C}; Step Recovery; see Figure 6 $	-	25	50	ns
	Parameter repetitive peak reverse voltage average forward current racteristics forward voltage characteristics	ParameterConditionsrepetitive peak reverse voltagesquare-wave pulse; $\overline{o} = 0.5$; see Figure 1; see Figure 2average forward currentsquare-wave pulse; $\overline{o} = 0.5$; see Figure 2macteristics $I_F = 4 \text{ A}; T_j = 25 \text{ °C};$ see Figure 4forward voltage $I_F = 4 \text{ A}; T_j = 25 \text{ °C};$ see Figure 4characteristics $I_F = 1 \text{ A}; V_R = 30 \text{ V};$ $dI_F/dt = 50 \text{ A}/\mus; T_j 25 \text{ °C};$ Ramp Recovery; see Figure 5 $I_R = 1 \text{ A}; I_F = 0.5 \text{ A};$ $I_R = 1 \text{ A}; I_F = 0.5 \text{ A};$ $I_R(meas) = 0.25 \text{ A}; T_j = 25 \text{ °C};$	$\begin{tabular}{ c c c c } \hline Parameter & Conditions & Min \\ \hline repetitive peak reverse \\ voltage & - \\ \hline everse forward \\ current & square-wave pulse; $\delta = 0.5; \\ see Figure 1; see Figure 2 & - \\ \hline everse recovery time \\ \hline forward voltage & I_F = 4 A; T_j = 25 \ ^C; \\ see Figure 4 & - \\ \hline everse recovery time \\ \hline I_F = 1 A; V_R = 30 V; \\ \hline everse recovery time & I_F = 1 A; V_R = 30 V; \\ \hline everse recovery time & I_F = 1 A; V_R = 30 V; \\ \hline everse recovery time & I_F = 1 A; V_R = 30 V; \\ \hline Ramp Recovery; \\ see Figure 5 & - \\ \hline I_R = 1 A; I_F = 0.5 A; \\ \hline I_R = 1 A; I_F = 25 \ ^C; \\ \hline everse recovery Time & I_F = 1 A; V_R = 30 V; \\ \hline everse Figure 5 & - \\ \hline everse Figure 5$	$\begin{tabular}{ c c c c c } \hline Parameter & Conditions & Min & Typ \\ \hline repetitive peak reverse \\ voltage & - & - \\ \hline expected average forward \\ current & square-wave pulse; \delta = 0.5; \\ see Figure 1; see Figure 2 & - & - \\ \hline expected see Figure 1; see Figure 2 & - & - \\ \hline expected see Figure 1; see Figure 2 & - & - \\ \hline expected see Figure 1; see Figure 2 & - & - \\ \hline expected see Figure 4 & - & - \\ \hline expected see Figure 4 & - & - \\ \hline expected see Figure 4 & - & - \\ \hline expected see Figure 5 & - & - & - \\ \hline expected see Figure 5 & - & - & - \\ \hline expected see Figure 5 & - & - & - \\ \hline expected see Figure 5 & - & - & - \\ \hline expected see Figure 5 & - & - & - \\ \hline expected see Figure 5 & - & - & - \\ \hline expected see Figure 5 & - & - & - \\ \hline expected see Figure 5 & - & - & - \\ \hline expected see Figure 5 & - & - & - \\ \hline expected see Figure 5 & - & - & - \\ \hline expected see Figure 5 & - & - & - \\ \hline expected see Figure 5 & - & - & - \\ \hline expected see Figure 5 & - & - & - \\ \hline expected set set set set set set set set set set$	ParameterConditionsMinTypMaxrepetitive peak reverse voltage600average forward currentsquare-wave pulse; $\delta = 0.5$; see Figure 1; see Figure 24macteristics4forward voltageIF = 4 A; Tj = 25 °C; see Figure 41.28characteristics1.28reverse recovery timeIF = 1 A; VR = 30 V; dIF/dt = 50 A/µs; Tj 25 °C; Ramp Recovery; see Figure 5-3365IR = 1 A; IF = 0.5 A; IR = 1 A; IF = 0.5 A; Tj = 25 °C;-2550



2. Pinning information

Table 2.	Pinning	information		
Pin	Symbol	Description	Simplified outline	Graphic symbol
1	К	cathode		
2	А	anode		K — A 001aaa020
			SOD141 (DO-201AD)	

3. Ordering information

Table 3.	Ordering i	nformation		
Type num	ber	Package		
		Name	Description	Version
NUR460		DO-201AD	Hermetically sealed plastic package; axial leaded; 2 leads	SOD141

4. Limiting values

Table 4.Limiting values

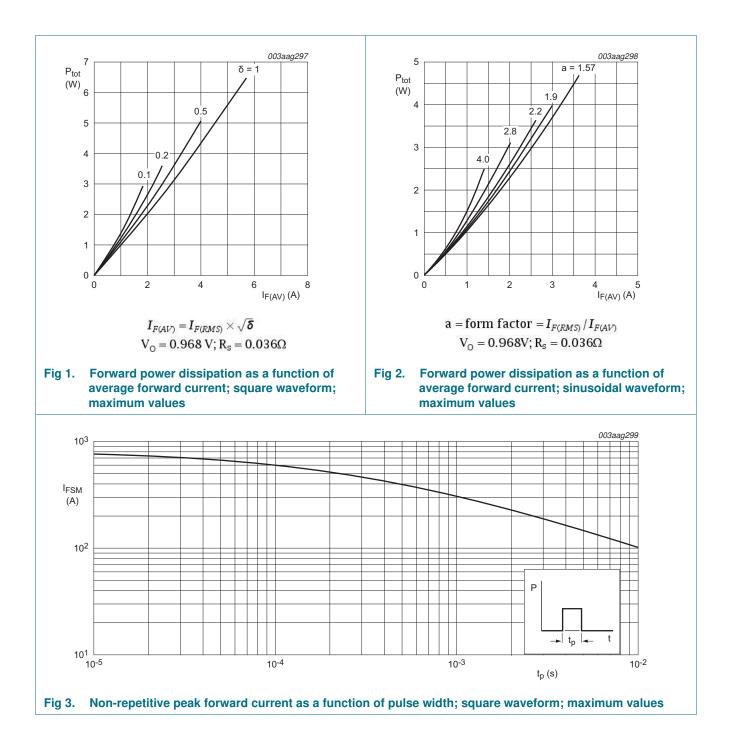
In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V _{RRM}	repetitive peak reverse voltage		-	600	V
V _{RWM}	crest working reverse voltage		-	600	V
V _R	reverse voltage	DC	-	600	V
I _{F(AV)}	average forward current	square-wave pulse; δ = 0.5 ; see <u>Figure 1;</u> see <u>Figure 2</u>	-	4	A
I _{FRM}	repetitive peak forward current	square-wave pulse; $\delta = 0.5$	-	8	А
I _{FSM}	non-repetitive peak forward current	t _p = 8.3 ms; sine-wave pulse; T _{j(init)} = 25 °C; see <u>Figure 3</u>	-	110	А
		t _p = 10 ms; sine-wave pulse; T _{j(init)} = 25 °C; see <u>Figure 3</u>	-	100	А
T _{stg}	storage temperature		-40	150	°C
Ti	junction temperature		-	150	°C

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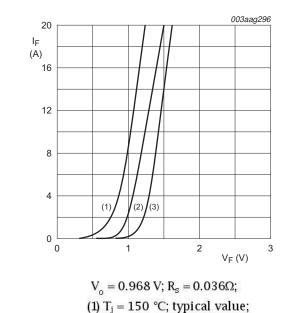


5. Thermal characteristics

Table 5.	Thermal characteristics					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
R _{th(j-a)}	thermal resistance from junction to ambient	in free air	-	55	-	K/W

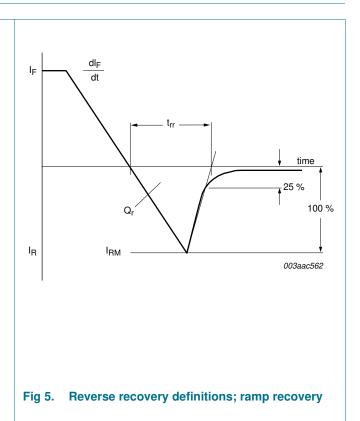
6. Characteristics

Table 6.	Characteristics					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static cha	aracteristics					
V _F	forward voltage	$I_F = 4 \text{ A}; T_j = 25 \text{ °C}; \text{ see } \frac{\text{Figure 4}}{1000 \text{ G}}$	-	-	1.28	V
		$I_F = 4 \text{ A}; T_j = 150 \text{ °C}; \text{ see } \frac{\text{Figure 4}}{1000 \text{ C}}$	-	0.88	1.05	V
I _R	reverse current	V _R = 600 V; T _j = 25 °C	-	-	50	μA
Dynamic	characteristics					
t _{rr}	reverse recovery time	$I_F = 1 A; V_R = 30 V; dI_F/dt = 50 A/\mu s;$ Ramp Recovery; $T_j 25 °C; see Figure 5$	-	33	65	ns
		I _F = 0.5 A; I _R = 1 A; Step Recovery; I _{R(meas)} = 0.25 A; T _j = 25 °C; see <u>Figure 6</u>	-	25	50	ns



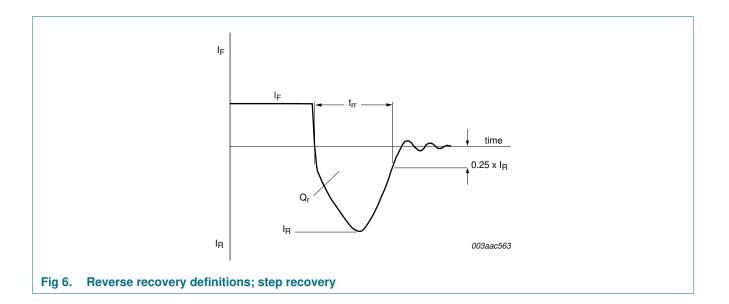
(1) T_j = 150 °C; typical value;
(2) T_j = 150 °C; maximum value;
(3) T_j = 25 °C; maximum value

Fig 4. Forward current as a function of forward voltage



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NUR460 Ultrafast power diode



Ultrafast power diode

7. **Package outline**

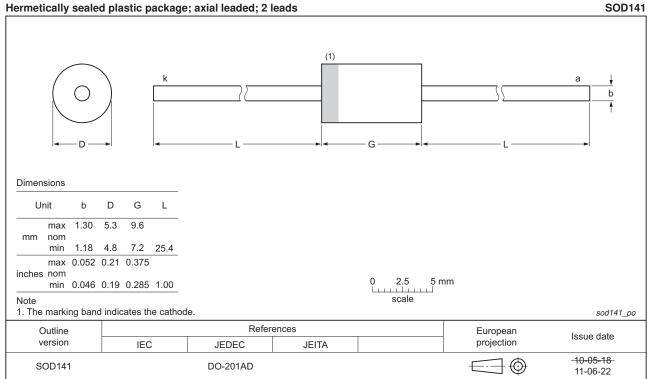


Fig 7. Package outline SOD141 (DO-201AD)

8. Revision history

Table 7.Revision h	listory			
Document ID	Release date	Data sheet status	Change notice	Supersedes
NUR460 v.2	20110720	Product data sheet	-	NUR460 v.1
Modifications:	 Various changes to 	o content.		
NUR460 v.1	20110704	Product data sheet	-	-

9. Legal information

9.1 Data sheet status

Document status [1] [2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

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Product data sheet

NUR460

Ultrafast power diode

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